

Solid State Broadband High Power Amplifier

1209 - BBM3K5OHM
500 – 2700 MHz / 50 Watts

The BBM3K5OHM (SKU 1209) is suitable for broadband mobile Jamming and band specific high power applications in the P/L/S frequency bands. This compact module utilizes high power advanced GaN devices that provide excellent power density, high efficiency, wide dynamic range and low distortions. Exceptional performance, long term reliability and high efficiency are achieved by employing advanced broadband RF matching networks and combining techniques, EMI/RFI filters, machined housings and qualified components. Empower RF's ISO9001 Quality Assurance Program assures consistent performance and the highest reliability.



- Solid-state Class AB design
- Instantaneous ultra broadband
- Small and lightweight
- Suitable for CW, AM, and FM (Contact factory for other modulation types)
- 50 ohm input/output impedance
- High reliability and ruggedness
- Built-in control, monitoring and protection circuits

ELECTRICAL SPECIFICATIONS @ +28.0V_{DC}, 25°C, 50Ω System

Parameter	Symbol	Min	Typ	Max	Unit
Operating Frequency	BW	500		2700	MHz
Output Power CW	P _{SAT}	50			Watt
Output Power @ 1dB Gain Compression	P _{1dB}		20		Watt
Small Signal Gain	G _{SS}	46	48		dB
Input Power for Rated P _{SAT}	P _{IN}		0	4	dBm
Small Signal Gain Flatness	ΔG _{SS}			±1.5	dB
Input Return Loss	S ₁₁			-10	dB
Noise Figure	NF			11.5	dB
Third Order Intercept Point 2-Tone @ 33dBm/Tone, 100kHz Spacing	IP3	+48	+53		dBm
Harmonics @ P _{OUT} = 20W	H		-20	-13	dBc
Spurious Signals	Spur		-70	-60	dBc
Operating Voltage	V _{DC}	26	28	30	Volt
Current Consumption @ P _{OUT} = 50W	I _{DD}			6.0	Amp
Quiescent Current	I _{DQ}		2.0		Amp
Current Consumption @ Shutdown	I _{SD}			400	mA
Switching Time @ 1kHz TTL, P _{IN} = 0 dBm	T _{ON} /T _{OFF}		2	5	uSec

MECHANICAL SPECIFICATIONS

Parameter	Value	Unit
Dimensions	7.4 x 3.6 x 1.1	Inch
Weight	1.0	Pound
RF Connectors Input/Output	Type-SMA, Female	J1/J2
DC Interface Connector	D-Sub 9-Pin, Male	J3
Cooling	External Heatsink (Not Supplied)	

ENVIRONMENTAL CHARACTERISTICS (Design to Meet)

Parameter	Symbol	Min	Typ	Max	Unit
Operating Case Temperature	T _C	-40		+80	°C
Storage Temperature	T _{STG}	-40		+85	°C
Relative Humidity (non-condensing)	RH			95	%
Altitude (MIL-STD-810F Method 500.4)	ALT			30,000	Feet
Vibration/Shock MIL-STD-810F - Method 514.5/516.5 – Proc I	VI/SH		Airborne		

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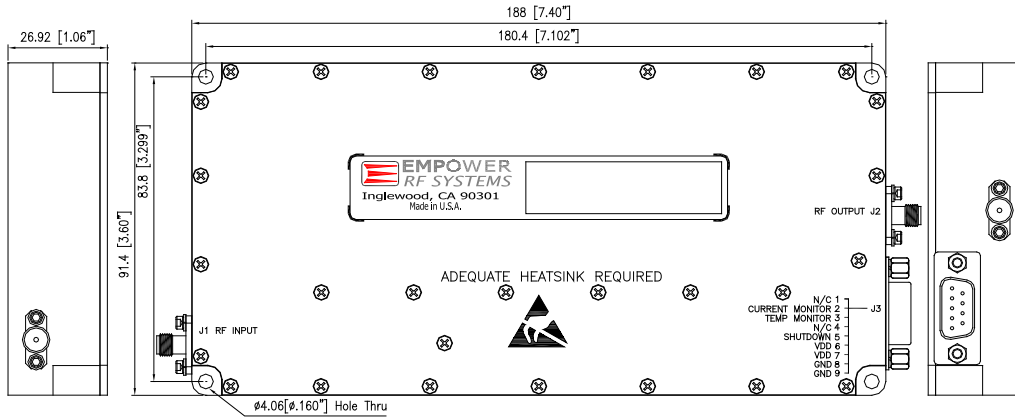
LIMITS

Input RF drive level without damage	+10 dBm	Max
Load VSWR @ P _{OUT} = 50W	∞ @ All load phase & amplitude for duration of 1 minute 3:1 @ all load phase & amplitude continuous	-
Thermal Degradation	85°C	Max

DC INTERFACE CONNECTOR – D-Sub 9-Pin, Male

Pin #	Description	Specification
1	N/C	No Connection
2	Current Monitor	Analog voltage relative to I _{DD} @ 50mV/100mA
3	Temp Monitor	Analog voltage relative to module's temperature @ 10mV/°C (i.e. 0.25V = 25°C)
4	N/C	No Connection
5	Shutdown	Amplifier Disable: TTL Logic High (5V) (Internally Pulled-Low)
6&7	VDD	+26.0-30.0V _{DC}
8&9	GND	Ground

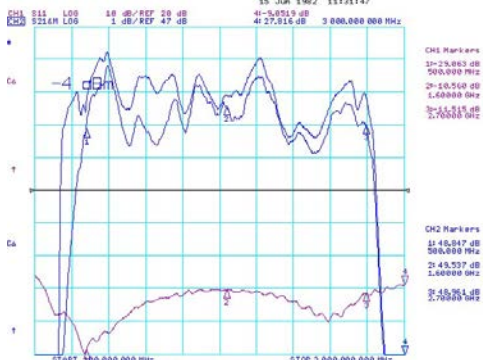
OUTLINE DRAWING



TYPICAL PERFORMANCE PLOTS

Plot 1 – Small Signal Gain and P_{1dB}

Top Curve: Small Signal Gain @ P_{IN} = -20dBm
 Middle Curve: Power Gain @ P_{1dB}, P_{IN} = -4.0dBm
 Reference: 47dB, 1dB/div.
 Bottom Curve: Input Return Loss
 Reference: 20dB, 10dB/div.



Plot 2 – Small Signal Gain and P_{SAT}

Top Curve: Small Signal Gain @ P_{IN} = -20dBm
 Middle Curve: Power Gain @ P_{SAT}, P_{IN} = 3.0dBm
 Reference: 47dB, 1dB/div.
 Bottom Curve: Input Return Loss
 Reference: 20dB, 10dB/div.

